We are grateful to the Deutsche Forschungsgemeinschaft, Bonn-Bad Godesberg, and Fonds der Chemischen Industrie, Frankfurt/Main, for continuous support.

Lists of structure factors, anisotropic displacement parameters. Hatom coordinates and complete geometry have been deposited with the IUCr (Reference: JZ1111). Copies may be obtained through The Managing Editor. International Union of Crystallography, 5 Abbey Square, Chester CH1 2HU, England.

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Acta Cryst. (1996). C52, 1184-1186
(Acridine)trimethylgallium-Acridine (2/1)
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(Received 10 January 1995; accepted 23 October 1995)


#### Abstract

The reaction of excess trimethylgallium with acridine in diethyl ether gave the title layer inclusion compound, $\left[\mathrm{Ga}\left(\mathrm{CH}_{3}\right)_{3}\left(\mathrm{C}_{13} \mathrm{H}_{8} \mathrm{~N}\right)\right] .0 .5 \mathrm{C}_{13} \mathrm{H}_{9} \mathrm{~N}$. The $\mathrm{Ga}-\mathrm{N}$ bond length is 2.203 (3) $\AA$.


## Comment

Metal-organic chemical vapour deposition (MOCVD) has become a powerful method for the preparation of thin films of electronic materials. A major effort has been concentrated on exploring the toxicity, stability and volatility of precursors for MOCVD (Bradley, Dawes, Hursthouse, Smith \& Thornton-Pett, 1990; Bradley, Frigo, Harding, Hursthouse \& Motevalli, 1992). The title compound, (I), was obtained and studied by X-ray analysis, revealing that the (acridine)trimethylgallium and free acridine molecules lie in layers.


Analysis of (I) (Fig. 1) shows that the asymmetric unit has one molecule of (acridine)trimethylgallium in a general position and an uncoordinated acridine molecule lying about an inversion centre (which requires that it be disordered). The Ga atom has distorted tetrahedral coordination, with $\mathrm{N}-\mathrm{Ga}-\mathrm{C}$ angles in the range $98.9(1)-108.3(1)^{\circ}$ and $\mathrm{C}-\mathrm{Ga}-\mathrm{C}$ angles in the range $107.5(1)-117.3(1)^{\circ}$. The $\mathrm{Ga}-\mathrm{N}$ distance of 2.203 (3) $\AA$ is slightly longer than previously reported


Fig. 1. The molecular structure of the title compound showing $50 \%$ probability displacement ellipsoids.
$\mathrm{Ga}-\mathrm{N}$ distances (Bradford, Bradley, Hursthouse \& Motevalli, 1992). We ascribe this to the steric hindrance of the acridine moiety. The plane composed of atoms $\mathrm{Cl}, \mathrm{C} 6-\mathrm{C} 9$ and N makes angles of $4.9(4)$ and $4.0(5)^{\circ}$ with the $\mathrm{C} 1-\mathrm{C} 6$ and $\mathrm{C} 8-\mathrm{C} 13$ rings, respectively.

The layer structure of the complex can be seen clearly in the packing diagram (Fig. 2). Free acridine molecules (disordered on inversion centres) are sandwiched between the acridine moieties of the (acridine)trimethylgallium molecules; the shortest interplanar separation is 3.926 (3) A and the two planes (coordinated and free acridine) are nearly parallel, with a dihedral angle of $1(1)^{\circ}$.


Fig. 2. The molecular packing in the unit cell.

## Experimental

The title product was prepared by reaction of acridine and $\mathrm{Me}_{3} \mathrm{Ga}$ (molar ratio 1:1.2) in $\mathrm{Et}_{2} \mathrm{O}$ for 4 h at room temperature. Removal of the solvent and recrystallization from cyclohexane afforded crystals suitable for analysis. All operations were carried out under an atmosphere of specially dried oxygenfree nitrogen using Schlenk tube techniques and a dry box. Solvents were carefully dried by distillation from sodium diphenyl ketone under nitrogen before use.

## Crystal data

$\left[\mathrm{Ga}\left(\mathrm{CH}_{3}\right)_{3}\left(\mathrm{C}_{13} \mathrm{H}_{9} \mathrm{~N}\right)\right]$.-
$0.5 \mathrm{C}_{13} \mathrm{H}_{9} \mathrm{~N}$
$M_{r}=383.66$
Triclinic
$P \overline{1}$
$a=9.474(1) \AA$
$b=9.529(2) \AA$
$c=12.160(2) \AA$
$\alpha=99.98(1)^{\circ}$
$\beta=97.16(1)^{\circ}$
$\gamma=115.92(1)^{\circ}$
$V=947.2 \AA^{3}$
$Z=2$
$D_{x}=1.343 \mathrm{Mg} \mathrm{m}^{-3}$
$D_{m}$ not measured

## Data collection

Enraf-Nonius CAD-4 diffractometer
$\omega / 2 \theta$ scans
Absorption correction:
refined from $\Delta F$
(DIFABS; Walker \&
Stuart, 1983)
$T_{\text {min }}=0.80, T_{\text {max }}=1.00$
3707 measured reflections 3527 independent reflections

2758 observed reflections
$[I>3 \sigma(I)]$
$R_{\text {int }}=0.02$
$\theta_{\text {max }}=26^{\circ}$
$h=-11 \rightarrow 11$
$k=-11 \rightarrow 11$
$l=0 \rightarrow 14$
2 standard reflections frequency: 60 min intensity decay: $8.6 \%$

## Refinement

Refinement on $F$
$R=0.0385$
$w^{\prime} R=0.0393$
$S=1.534$
2758 reflections
226 parameters
Only coordinates of H atoms refined
$w=1 /\left[\sigma^{2}\left(F_{"}\right)+\left(0.0 \mid F_{4}\right)^{2}\right.$
$+1.0]$
$(\Delta / \sigma)_{\max }<0.001$
$\Delta \rho_{\text {max }}=0.262 \mathrm{e}^{\AA^{-3}}$
$\Delta \rho_{\text {min }}=-0.445 \mathrm{e}^{-3}$
Extinction correction: none Atomic scattering factors from International Tables for X-ray Crystallography (1974, Vol. IV)

Table 1. Fractional atomic coordinates and equivalent isotropic displacement parameters ( $\AA^{2}$ )

| $B_{\text {cq }}=(4 / 3) \sum_{i} \sum_{j} \beta_{i j} \mathbf{a}_{i} \cdot \mathbf{a}_{j}$. |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | $x$ | $y$ | こ | $B_{\text {eq }}$ |
| Ga | 0.38354 (4) | 0.39712 (4) | 0.21437 (3) | 3.766 (8) |
| N | (). 1584 (3) | 0.4147 (3) | 0.1828 (2) | 3.23 (6) |
| C1 | 0.0204 (3) | 0.3026 (3) | 0.2034 (2) | 3.32 (7) |
| C2 | 0.0073 (4) | 0.1523 (4) | 0.2164 (3) | 4.19 (8) |
| C. 3 | -0.1299 (4) | $0.04(0)(4)$ | 0.2372 (3) | 5.0 (1) |
| C4 | -0.2618(4) | 0.0672 (4) | 0. 2475 (3) | 5.2 (1) |
| C5 | -0.2555 (4) | 0. 2056 (4) | 0.2332 (3) | 5.)(1) |
| C6 | -0.1161 (3) | 0.3285 (4) | 0.2093 (3) | 3.76 (8) |
| C7 | -0.1086 (3) | 0.4690)(4) | 0.1880(3) | 4.45 (8) |
| C8 | 0.0242 (4) | 0.5779 (3) | 0.1574 (3) | 3.89 (8) |
| C9 | 0.1579 (3) | 0.5462 (3) | 0.1544 (3) | 3.55 (7) |
| Cl0 | 0.2905 (4) | 0.6552 (4) | 0.1175 (3) | 4.45 (9) |
| CII | 0.2902 (4) | 0.7860 (4) | 0.0880 (3) | 5.3 (1) |
| Cl 2 | 0.1601 (5) | 0.8187(4) | 0.0931 (3) | 5.7 (1) |
| C13 | 0.0315 (4) | 0.7180(4) | 0.1257 (3) | 5.4 (1) |
| C14 | 0.3688 (4) | 0.2844 (4) | 0.0576 (3) | 5.9 (1) |
| Cl 15 | 0.5613 (4) | 0.6191 (5) | 0.2756(3) | 5.9 (1) |
| C16 | 0.3768 (4) | 0.2820(4) | $0.3351(3)$ | 6.0)(1) |
| C21 | 1.0012 (3) | $0.3621(3)$ | 0.5207 (3) | 3.69 (8) |
| C22 | $0.8628(3)$ | 0.3860)(4) | 0.52 .38 (3) | 3.80 (8) |
| C23 | 0.7262 (4) | 0.2640)(4) | 0.5487 (3) | 4.76 (9) |
| C24 | 0.7274 (4) | 0.1300)(4) | 0.5697 (3) | 5.3 (1) |
| C25 | 0.8647 (4) | 0.1077 (4) | 0.5667 (3) | 5.3 (1) |
| C26 | 0.9972 (4) | 0.2193 (4) | 0.5427 (3) | 4.57 (9) |
| $M \dagger$ | 1.1380 (3) | $0.4793(3)$ | 0.4977 (3) | 3.51 (7) |

$\dagger M=\frac{1}{2}(\mathrm{C}+\mathrm{N})$.
Table 2. Selected geometric parameters $(\AA, \circ)$

| $\mathrm{Ga}-\mathrm{N}$ | $2.203(3)$ | $\mathrm{N}-\mathrm{C} 9$ | $1.358(4)$ |
| :--- | :--- | :--- | :--- |
| $\mathrm{Ga}-\mathrm{Cl} 4$ | $1.975(3)$ | $\mathrm{C} 21-\mathrm{M}$ | $1.392(4)$ |
| $\mathrm{N}-\mathrm{Cl}$ | $1.366(4)$ |  |  |
| $\mathrm{Ga}-\mathrm{N}-\mathrm{Cl}$ | $120.8(2)$ | $\mathrm{N}-\mathrm{Ga}-\mathrm{C} 15$ | $107.1(1)$ |
| $\mathrm{Ga}-\mathrm{N}-\mathrm{C} 9$ | $120.6(2)$ | $\mathrm{N}-\mathrm{Ga}-\mathrm{C} 16$ | $108.3(1)$ |
| $\mathrm{N}-\mathrm{Ga}-\mathrm{C} 14$ | $98.9(1)$ |  |  |

H atoms were located on a difference map and refined with isotropic displacement parameters.

Data collection: CAD-4 Software (Enraf-Nonius, 1985a).
Cell refinement: CAD-4 Software. Data reduction: SDP
(Enraf-Nonius, 1985b). Program(s) used to solve structure: MULTAN11/82 (Main et al., 1982). Program(s) used to refine structure: SDP. Molecular graphics: ORTEP (Johnson, 1965). Software used to prepare material for publication: SDP OMEGA.

Lists of structure factors, anisotropic displacement parameters, H atom coordinates, complete geometry and least-squares-planes data have been deposited with the IUCr (Reference: FGl063). Copies may be obtained through The Managing Editor. International Union of Crystallography, 5 Abbey Square, Chester CHI 2 HU , England.

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Acta Cryst. (1996). C52, 1186-1188

## Diammine(dimethylmalonato)platinum(II) Monohydrate

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(Received 22 June 1994: accepted 27 Oclober 1995)


#### Abstract

The complex molecule of the title compound, $\left[\mathrm{Pt}\left(\mathrm{C}_{5} \mathrm{H}_{6}-\right.\right.$ $\left.\left.\mathrm{O}_{4}\right)\left(\mathrm{NH}_{3}\right)_{2}\right] \cdot \mathrm{H}_{2} \mathrm{O}$, assumes a boat conformation that is more planar than expected from an optimization of bond


lengths and angles. Likely origins of this extra flattening are the repulsion between the Pt centre and the methyl group in the axial position, and hydrogen bonding with the water of crystallization.

## Comment

Fig. 1 shows an ORTEPII (Johnson, 1976) drawing of the complex molecule, and Fig. 2 shows the crystal packing. The complex of the title compound, (I), possesses a mirror plane which contains the $\mathrm{Pt}, \mathrm{C}(2), \mathrm{C}(3)$ and $\mathrm{C}(4)$ atoms, and is perpendicular to the Pt coordination plane. The Pt atom exhibits usual square-planar coordination. The $\mathrm{Pt}-\mathrm{N}$ and $\mathrm{Pt}-\mathrm{O}$ bond distances are as expected for the cis- $\mathrm{PtN}_{2} \mathrm{O}_{2}$ chromophore (Rochon, Melanson, Macquet, Bellanger-Gariepy \& Beauchamp, 1985, and references therein). There is one water molecule present in the lattice (Fig. 2), which is connected by hydrogen bonding to both ammine ligands of one molecule and to one carbonyl O atom $[\mathrm{O}(2)]$ of each of two other molecules. The compound is isostructural with the recently determined cyclopropylmalonato derivative (Dong et al., 1990).

(I)

The molecule adopts a boat conformation, with the Pt and $\mathrm{C}(2)$ atoms at the bow and the stern, respectively, similar to that found in other malonato complexes of platinum(II) (Rochon, Melanson, Macquet, BellangerGariepy \& Beauchamp, 1985; Dong et al., 1990). As in these complexes, the boat is flattened at the Pt end, with $\mathrm{O}-\mathrm{Pt}-\mathrm{O}-\mathrm{C}$ torsion angles of $\pm 41^{\circ}$ (instead of $\pm 60^{\circ}$ if all the bond angles were tetrahedral) (Table 4). The C 2 end of the boat is flattened as well, with $\mathrm{C}-\mathrm{C}-\mathrm{C}-\mathrm{O}$ torsion angles of $\pm 44^{\circ}$ (Table 4). In order to find out whether this flattening is simply due to the strain introduced to the six-membered ring by the two perpendicular $\mathrm{Pt}-\mathrm{O}$ bonds of $2.00(6) \AA$, we have constructed energy-minimized models using the program $A M B E R$ (Weiner \& Kollman, 1981). The energy function contained only bond and bond angle terms. The energy minimization resulted in a completely relaxed boat structure, with the bond lengths and bond angles having exactly the required values. The torsion angles of the relaxed model are given in Table 4. Their comparison with the experimental values shows that the boat is flattened at both ends more than expected for

